

Supplementary Information

Kinetics and Mechanism of BaLaCuS₃ Oxidation

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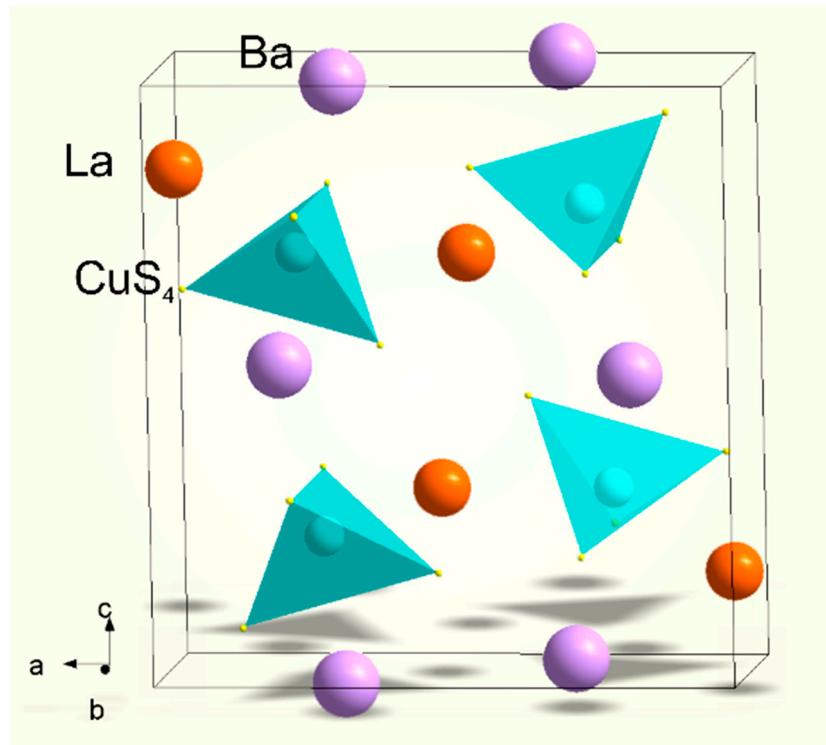
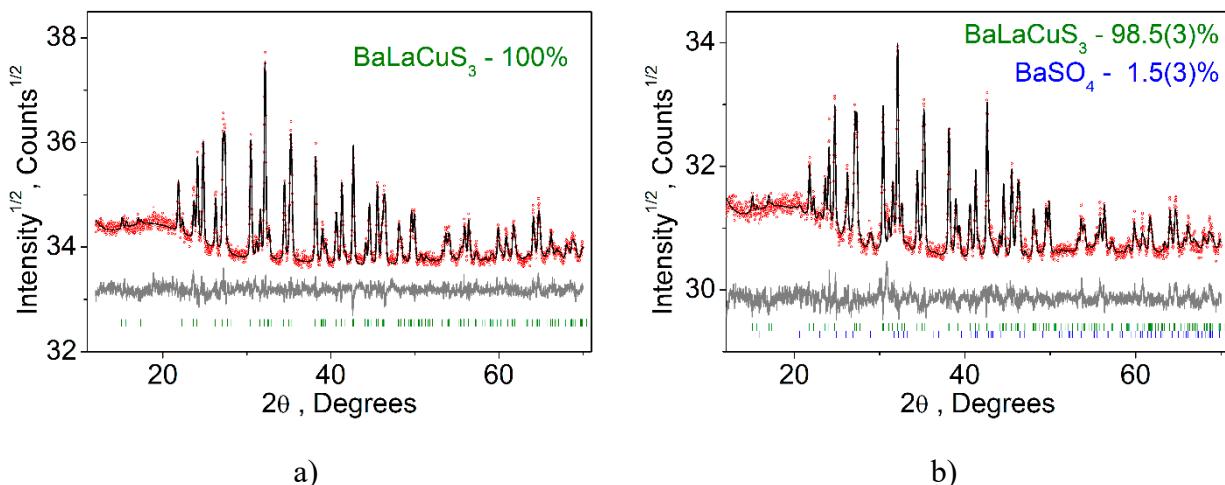
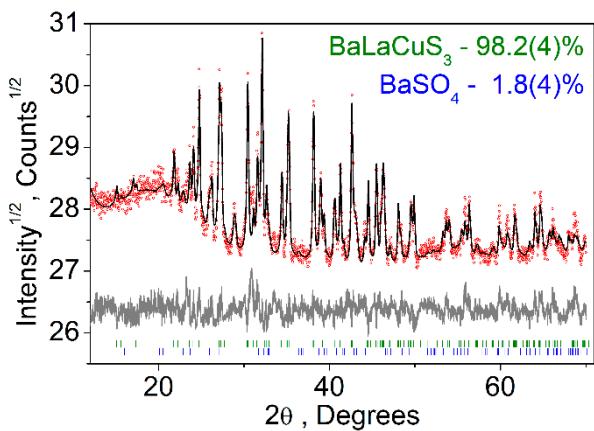
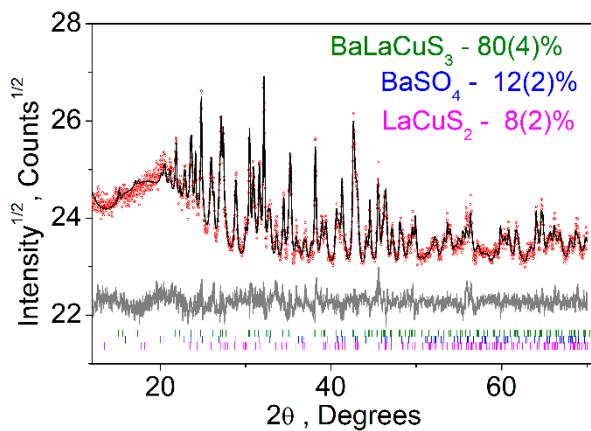


Figure S1. Crystal structure of BaLaCuS_3

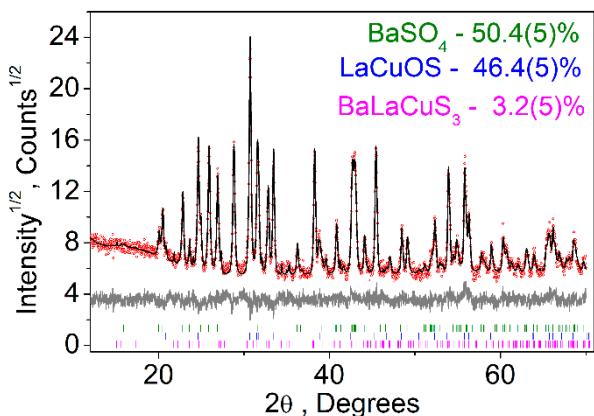




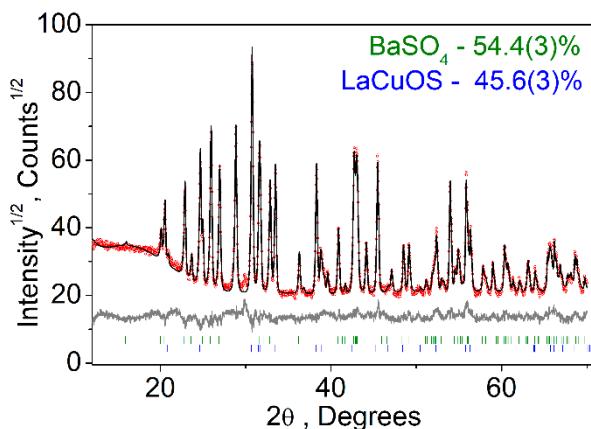
c)



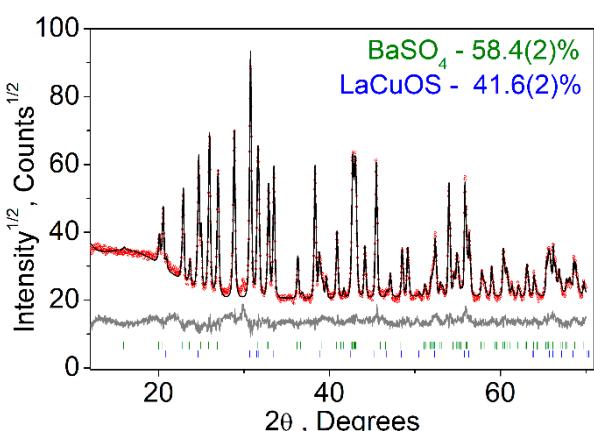
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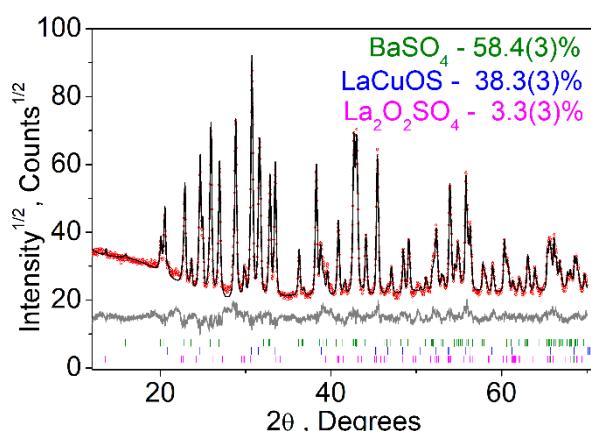
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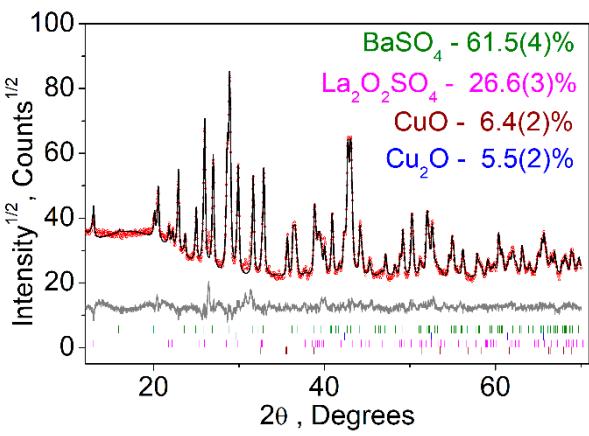
f)



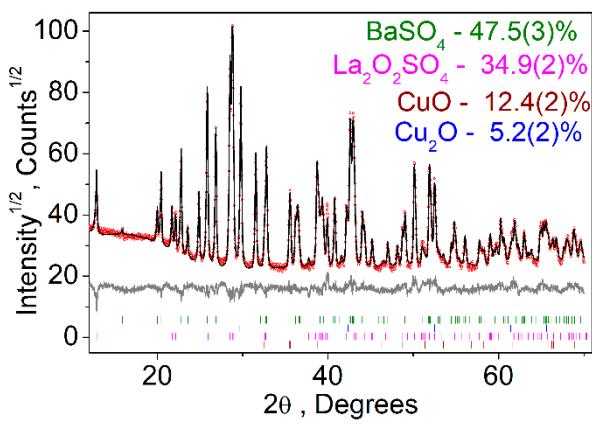
g)



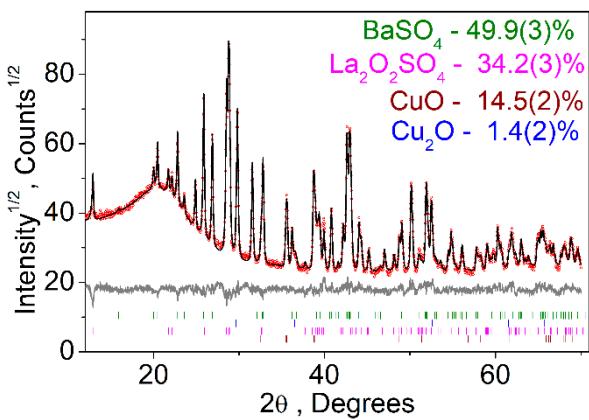
h)



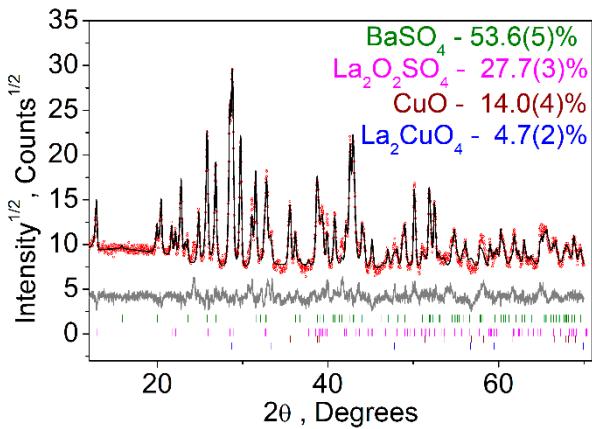
i)



j)

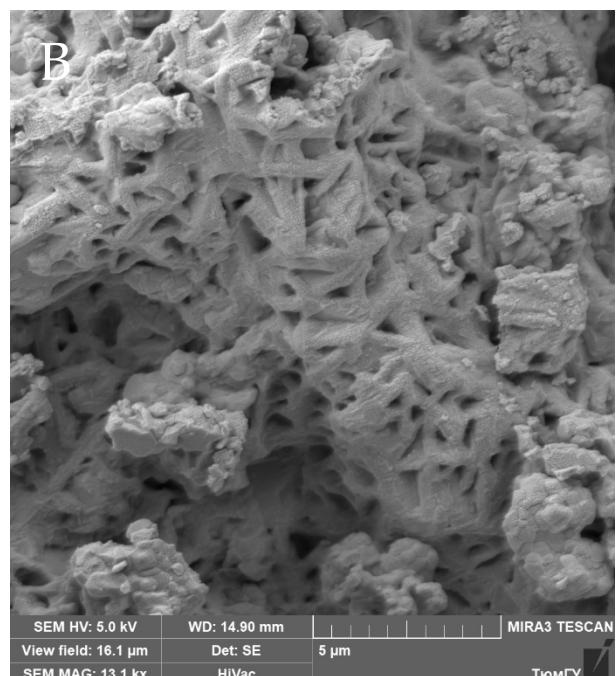
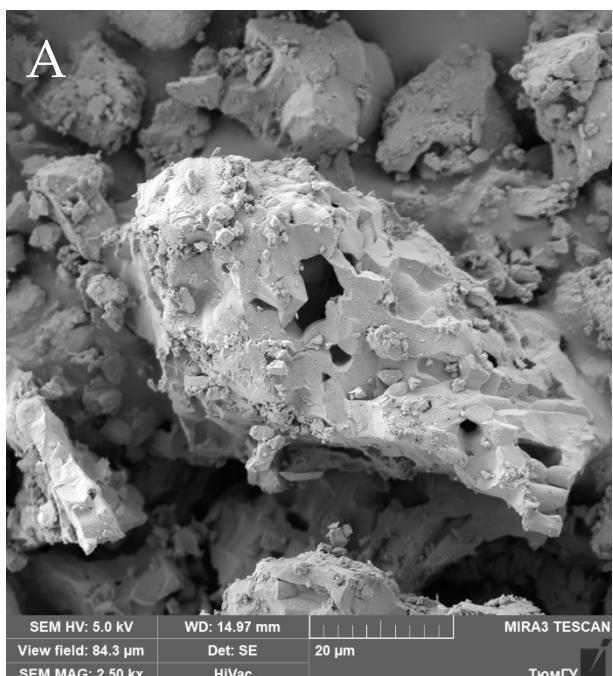


k)



l)

Figure S2. Difference Rietveld plot of BaLaCuS_3 at temperature: a) $T = 380 \text{ }^\circ\text{C}$; b) $T = 518 \text{ }^\circ\text{C}$; c) $T = 560 \text{ }^\circ\text{C}$; d) $T = 630 \text{ }^\circ\text{C}$; e) $T = 760 \text{ }^\circ\text{C}$; f) $T = 790 \text{ }^\circ\text{C}$; g) $T = 872 \text{ }^\circ\text{C}$; h) $T = 940 \text{ }^\circ\text{C}$; i) $T = 1020 \text{ }^\circ\text{C}$; j) $T = 1045 \text{ }^\circ\text{C}$; k) $T = 1137 \text{ }^\circ\text{C}$; l) $T = 1165 \text{ }^\circ\text{C}$.



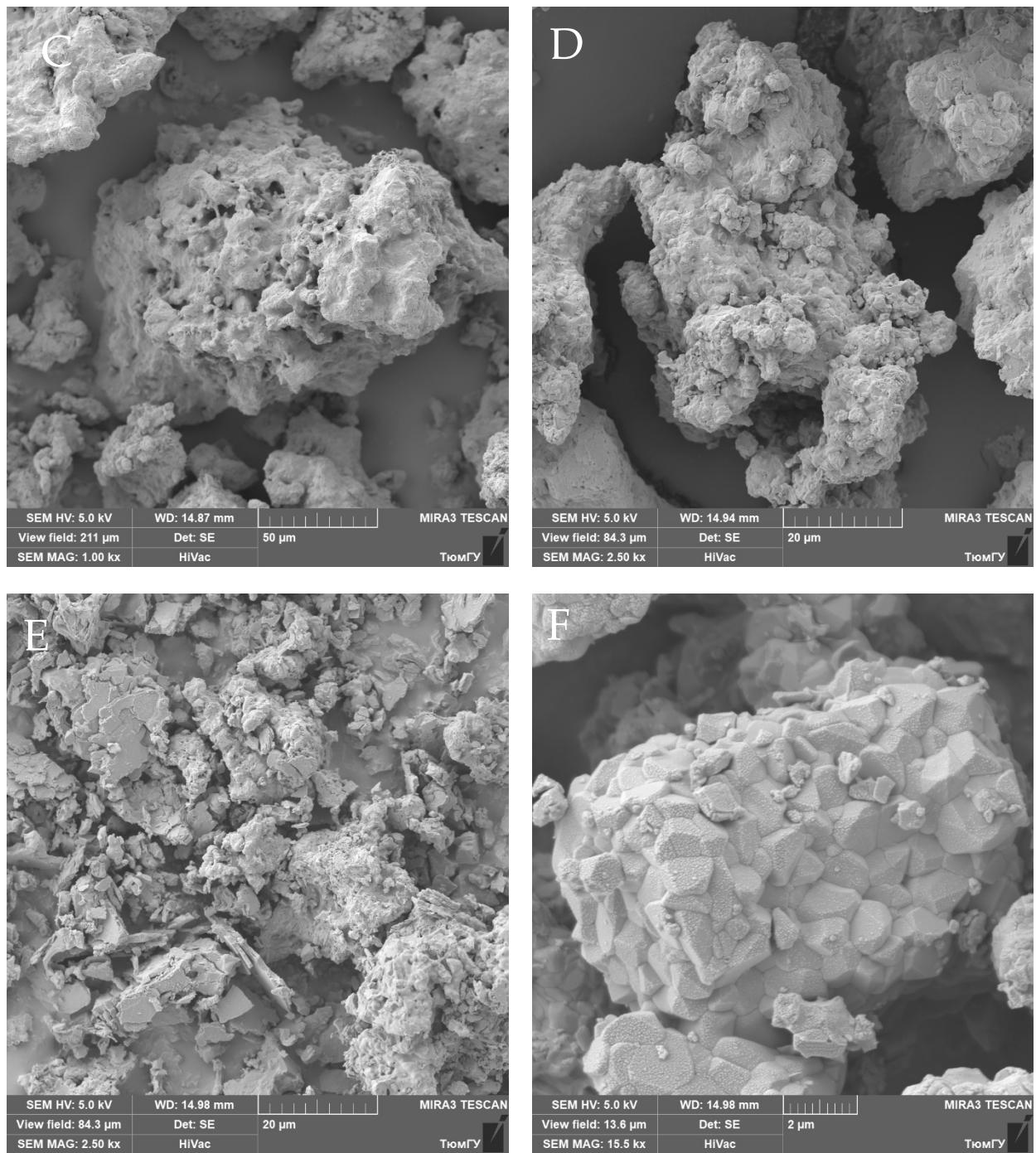


Figure S3. SEM patterns recorded for the intermediate products of the BaLaCuS₃ oxidation. A – first state at 380°C, B – at 650 °C, C – at 900 °C, D – 1000 °C, E – 1100 °C, F – 1200 °C.

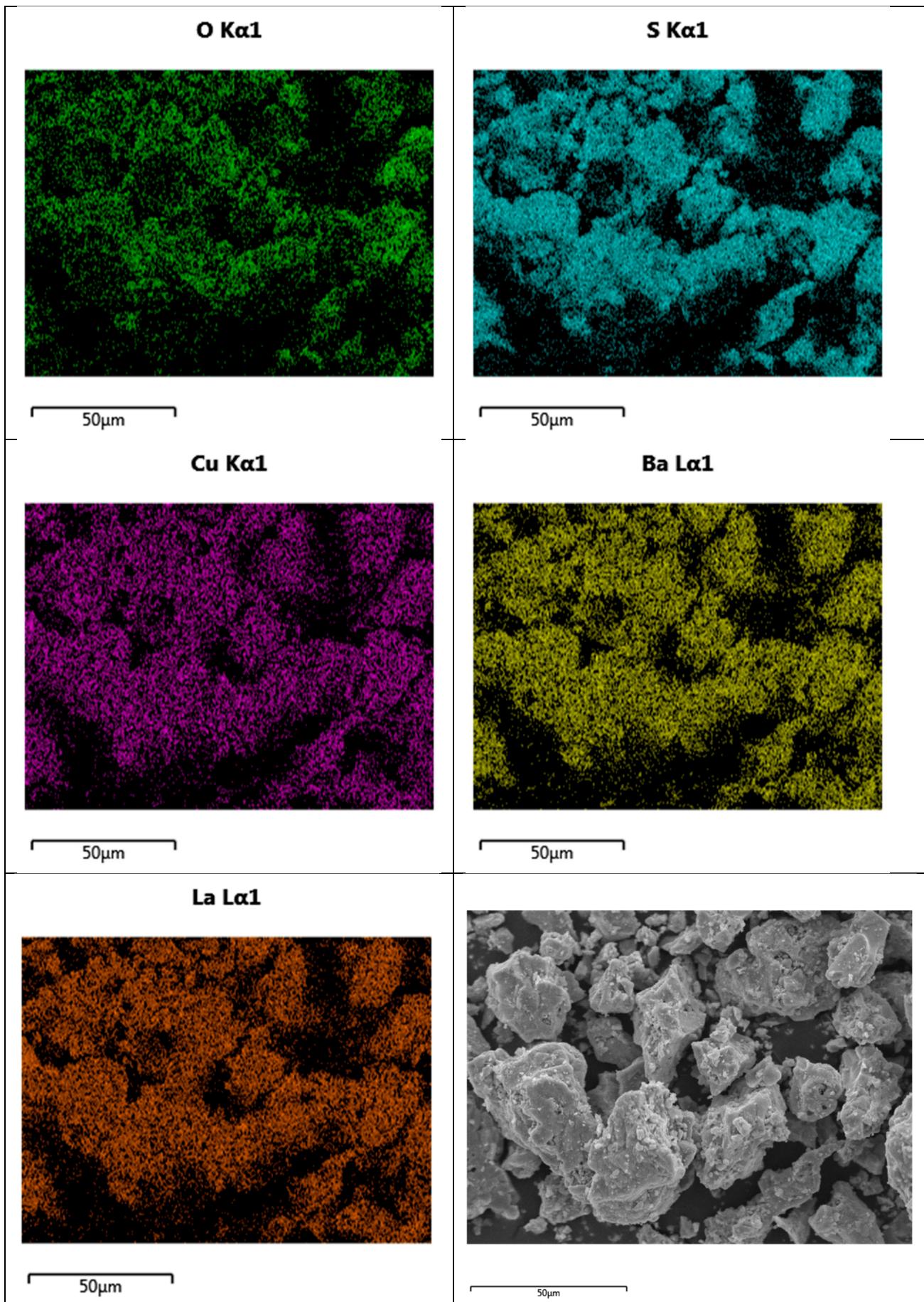


Figure S4. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃ oxidation at 380°C

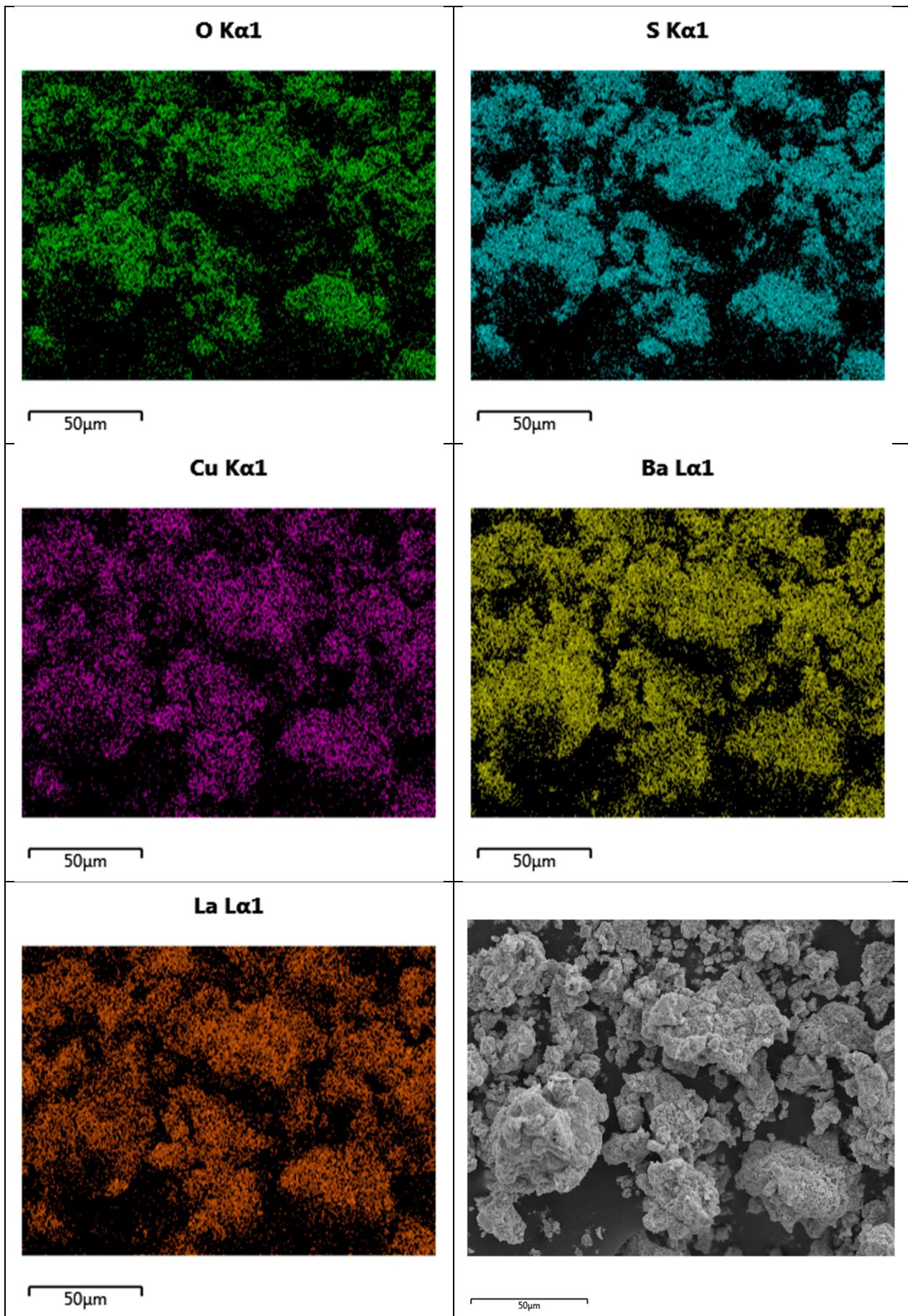


Figure S5. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃ oxidation at 650°C

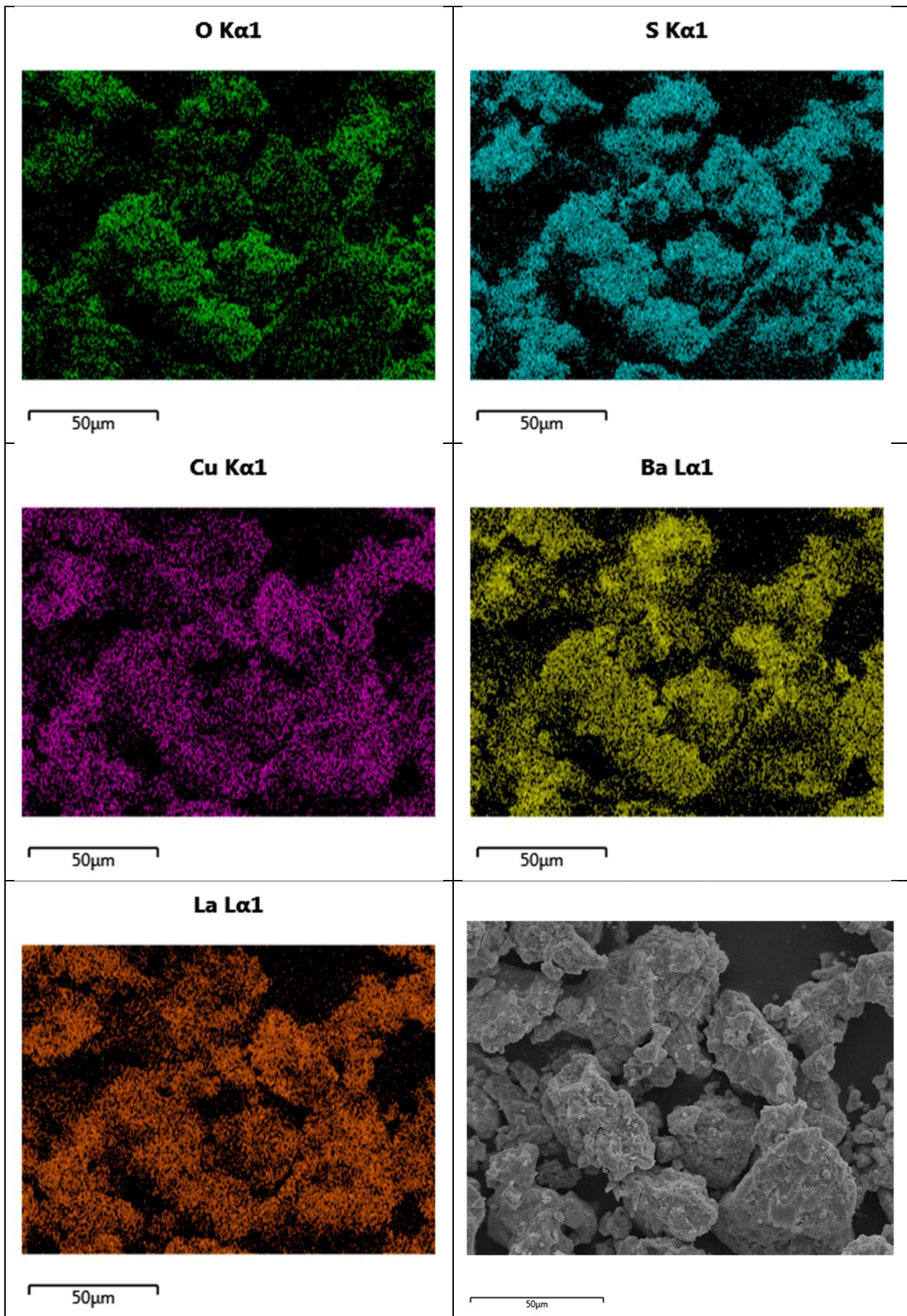


Figure S6. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃ oxidation at 900 °C

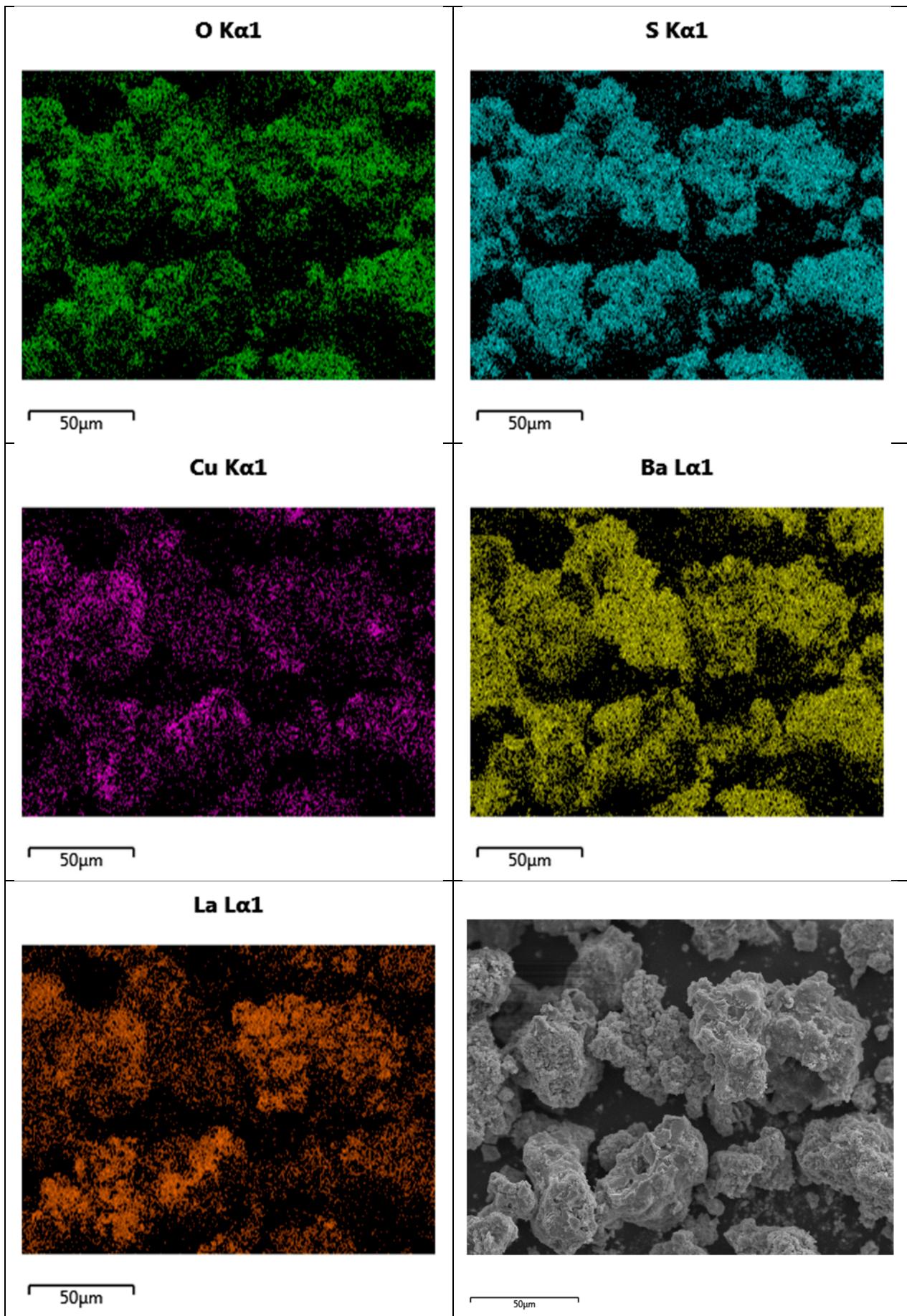


Figure S7. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃ oxidation at 1000 °C

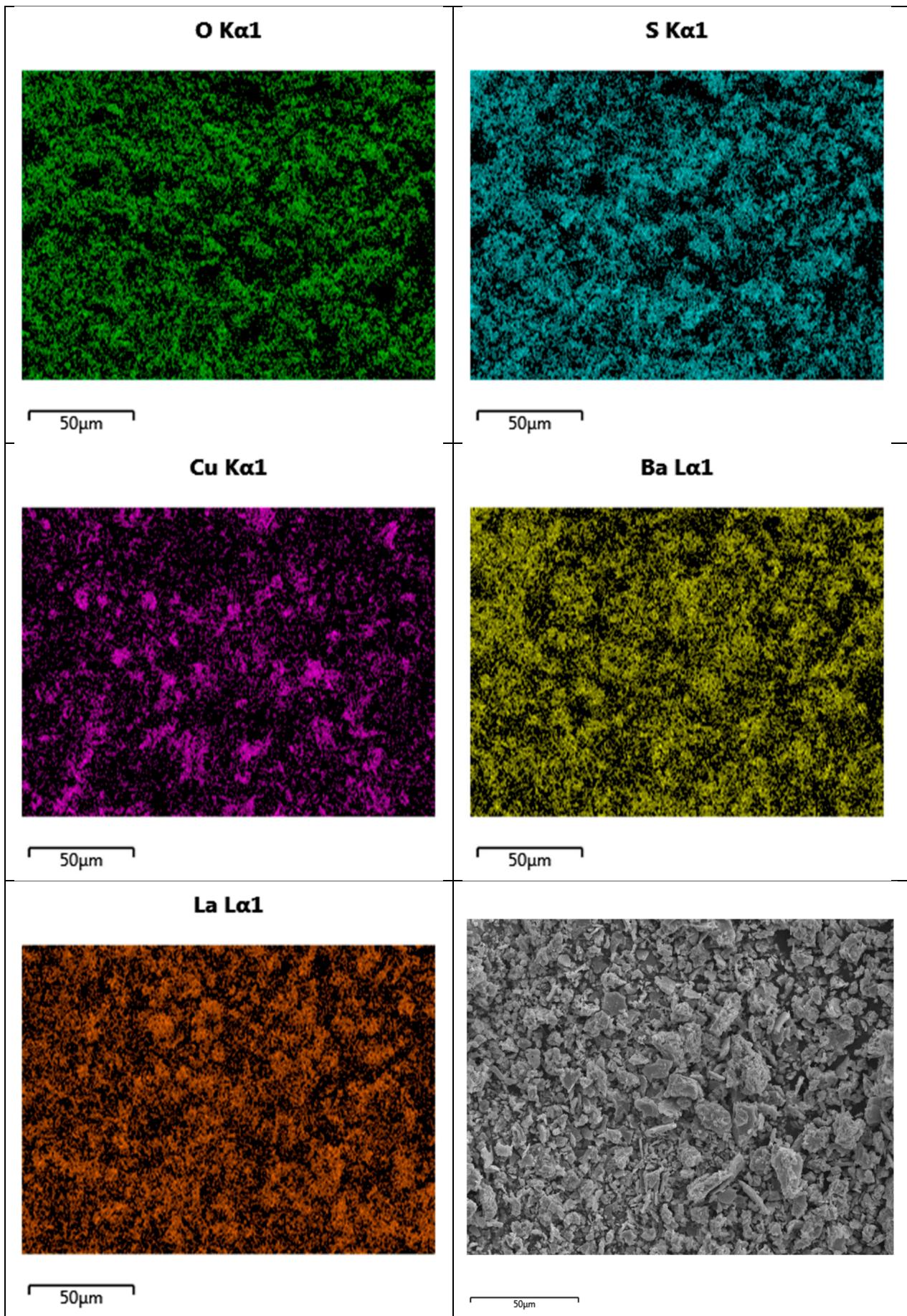


Figure S8. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS_3 oxidation at $1100\text{ }^\circ\text{C}$

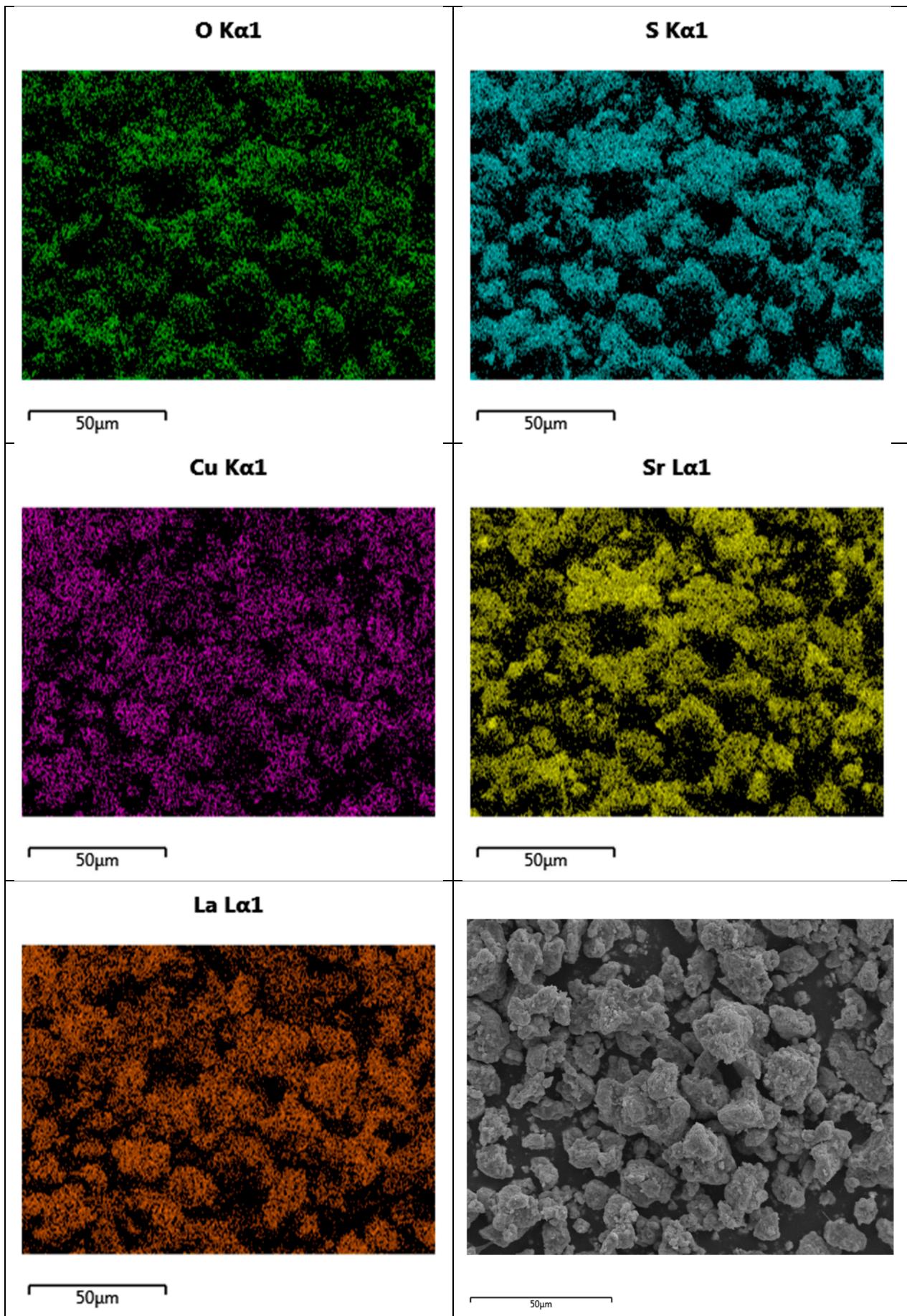


Figure S9. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃ oxidation at 1200 °C

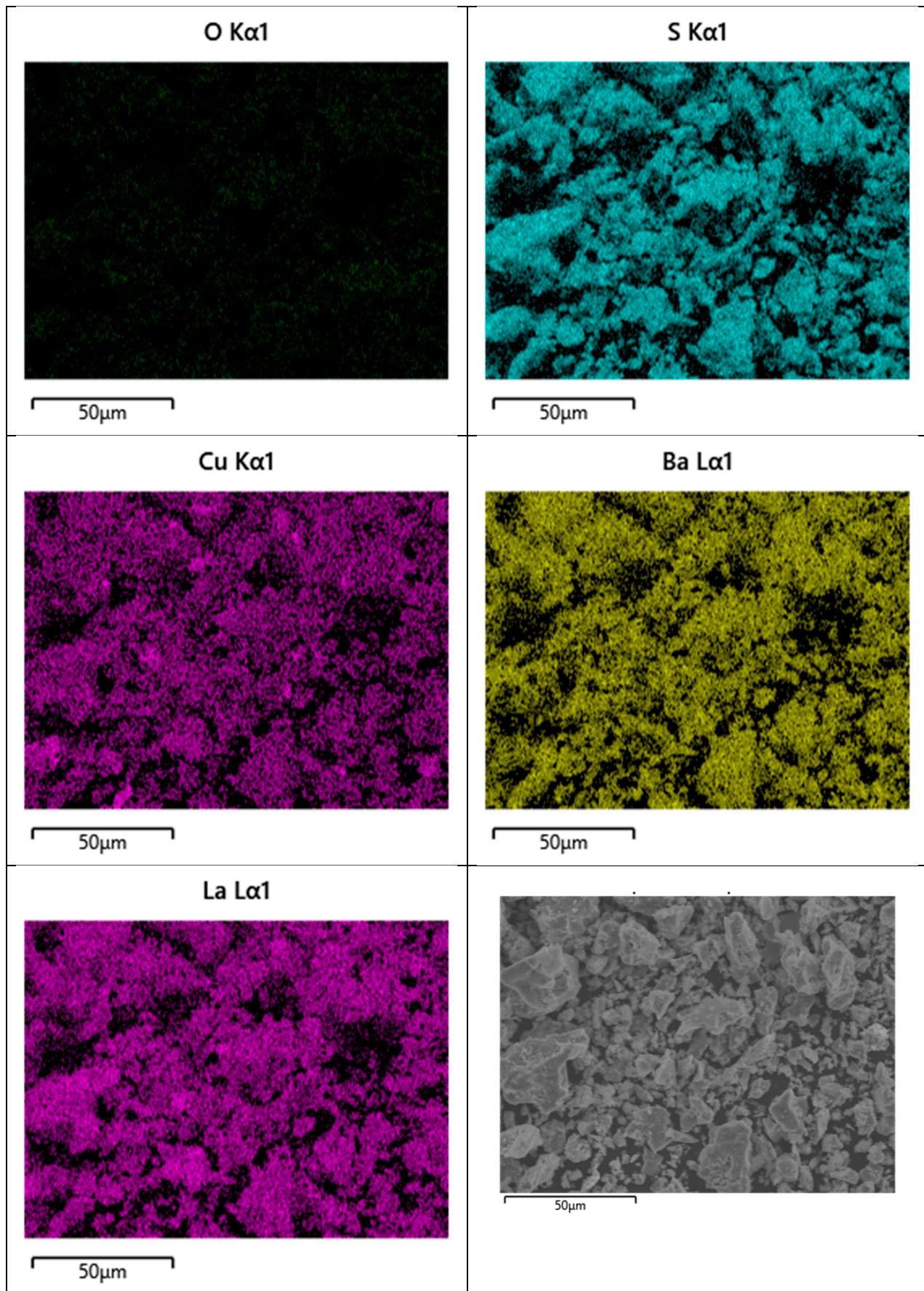


Figure S10. SEM and Energy dispersive X-ray (EDX) mapping analysis of BaLaCuS₃

Table S1. Fractional atomic coordinates and isotropic displacement parameters (\AA^2) of BaLaCuS₃

Atom	<i>x</i>	<i>y</i>	<i>z</i>	<i>B</i> _{iso}	<i>Occ.</i>
La	-0.01065(4)	0.25	0.81895(4)	0.201(19)	1
Ba	0.31635(3)	0.25	0.00671(4)	0.201(19)	1
Cu	0.24522(9)	0.25	0.29110(8)	0.96(3)	1
S1	0.04955(14)	0.25	0.35169(14)	0.40(4)	1
S2	0.22578(14)	0.25	0.70312(14)	0.56(5)	1
S3	0.38852(15)	0.25	0.44404(14)	0.30(4)	1

Table S2. Main bond lengths (\AA) of BaLaCuS₃

La—S1 ⁱ	2.9530(11)	La—S2	3.0076(16)
La—S2 ⁱⁱ	3.0019(16)	La—S3 ⁱⁱⁱ	2.9310(11)
La—S3 ⁱⁱ	3.0078(17)	Ba—S1 ^{iv}	3.1844(12)
Ba—S1 ^v	3.1247(16)	Ba—S2 ^{iv}	3.1713(12)
Ba—S3 ^{iv}	3.2342(13)	Cu—S1	2.3314(18)
Cu—S2 ^{iv}	2.38524(85)	Cu—S3	2.4220(19)

Symmetry codes: (i) -*x*, *y*+1/2, -*z*+1; (ii) *x*+1/2, -*y*+1/2, -*z*+3/2; (iii) -*x*+1/2, -*y*, *z*+1/2; (iv) -*x*+1/2, -*y*, *z*+1/2; (v) *x*+1/2, -*y*+1/2, -*z*+1/2;

Table S3. Main parameters of processing and refinement of the BaLaCuS₃ samples after heating to specified temperature and cooling

T, C	Phase	Weight, %	R _{wp} , R _p (%)
380	BaLaCuS ₃	100	0.52, 0.40
518	BaLaCuS ₃	98.5(3)	0.65, 0.49
	BaSO ₄	1.5(3)	
560	BaLaCuS ₃	98.2(4)	0.98, 0.76
	BaSO ₄	1.8(4)	
630	BaLaCuS ₃	80(4)	1.18, 0.91

	BaSO ₄	12(2)	
	LaCuS ₂	8(2)	
	BaLaCuS ₃	50.4(5)	
760	BaSO ₄	46.4(5)	9.17, 7.24
	BaLaCuS ₃	3.2(5)	
790	BaSO ₄	54.4(3)	8.36, 6.60
	LaCuOS	45.6(3)	
872	BaSO ₄	58.4(2)	7.06, 5.47
	LaCuOS	41.6(2)	
	BaSO ₄	58.4(3)	
940	LaCuOS	38.3(3)	7.45, 5.77
	La ₂ O ₂ SO ₄	3.3(3)	
	BaSO ₄	61.5(4)	
1020	La ₂ O ₂ SO ₄	26.6(3)	6.98, 5.16
	CuO	6.4(2)	
	Cu ₂ O	5.5(2)	
	BaSO ₄	47.5(3)	
1045	La ₂ O ₂ SO ₄	34.9(2)	6.80, 5.27
	CuO	12.4(2)	
	Cu ₂ O	5.2(2)	
	BaSO ₄	49.9(3)	
1137	La ₂ O ₂ SO ₄	34.2(3)	5.33, 4.05
	CuO	14.5(2)	
	Cu ₂ O	1.4(2)	
	BaSO ₄	53.6(5)	
1165	La ₂ O ₂ SO ₄	27.7(3)	10.48, 7.84
	CuO	14.0(4)	
	La ₂ CuO ₄	4.7(2)	